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## Quad SPST +70V Analog Switches


#### Abstract

General Description The MAX14756/MAX14757/MAX14758 are analog switches with a low on-resistance of $10 \Omega$ (max) that conduct equally well in both directions. All devices have a rail-to-rail analog-signal range. They operate with a single +10 V to +70 V supply in unipolar applications or $\pm 35 \mathrm{~V}$ dual supplies in bipolar applications. The bipolar supplies can be offset and do not have to be symmetrical. The MAX14756 is a quad normally closed (NC) single-pole/single-throw (SPST) switch, the MAX14757 is a quad normally open (NO) SPST switch, and the MAX14758 has two NO and two NC SPST switches. These switches have $5 \Omega$ (typ) on-resistances and low on-leakage currents of 0.01 nA (typ). The on-resistance flatness is $0.004 \Omega$ (typ).

The devices are suitable for a multitude of analog signal routing and switching applications. They are specified over an extended temperature range of $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$, but can be operated up to $+125^{\circ} \mathrm{C}$ with elevated leakage currents.


| Industrial Control Systems |
| :--- |
| Instrumentation |
| Battery Management |
| Environmental Control Systems |
| Medical Systems |
| ATE System |
| Audio Signal Routing/Switching |
| Automotive |

Features

- Single-Supply Operation from +10 V to +70 V
- Bipolar-Supply Operation Up to $\pm 35 \mathrm{~V}$
- On-Resistance of $10 \Omega$ (max)
- RoN Flatness of $0.004 \Omega$ (typ)
- 2.5 nA (max) Off-Leakage Currents at $+85^{\circ} \mathrm{C}$
- Overvoltage/Undervoltage Clamping Through Protection Diodes
- 500 A (typ) Supply Current
- TSSOP 16-Pin Package
- $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ Ambient Temperature Range
- Functionally Compatible to DG411, DG412, and DG413
- Functionally Operational Up to $+125^{\circ} \mathrm{C}$

Ordering Information

| PART | FUNCTION | TEMP <br> RANGE | PIN- <br> PACKAGE |
| :---: | :---: | :---: | :---: |
| MAX14756EUE+ | Quad NC <br> SPST | $-40^{\circ} \mathrm{C}$ to <br> $+85^{\circ} \mathrm{C}$ | 16 TSSOP |
| MAX14757EUE+ | Quad NO <br> SPST | $-40^{\circ} \mathrm{C}$ to <br> $+85^{\circ} \mathrm{C}$ | 16 TSSOP |
| MAX14758EUE+ + | Dual NO + <br> NC SPST | $-40^{\circ} \mathrm{C}$ to <br> $+85^{\circ} \mathrm{C}$ | 16 TSSOP |

+Denotes a lead(Pb)-free/RoHS-compliant package.

Functional Diagrams


## Quad SPST +70V Analog Switches

## ABSOLUTE MAXIMUM RATINGS

$V_{D D}$ to $V_{S S}$
. 0.3 V to +72 V
VSS to GND $\qquad$ -36 V to +0.3 V
VL, EN_ to GND ........-0.3V to the lesser of ( $+12 \mathrm{~V}, \mathrm{~V} D \mathrm{DD}+0.3 \mathrm{~V}$ )
 (whichever occurs first)
Continuous Current into $A_{-}, B_{-}$ .................................. $\pm 100 \mathrm{~mA}$

| Continuous Power Dissipation ( $\mathrm{T}_{\mathrm{A}}=+70$ TSSOP (derate $11.1 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above +70 |  |
| :---: | :---: |
| Operating Temperature Range. | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Junction Temperature | $+150^{\circ} \mathrm{C}$ |
| Lead Temperature (soldering, 10s) | $+300^{\circ} \mathrm{C}$ |
| Soldering Temperature (reflow) | $+260^{\circ} \mathrm{C}$ |

SSOP (derate $11.1 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $+70^{\circ} \mathrm{C}$ ) ................. 889 mW
Operating Temperature Range .......................... $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
Storage Temperature Range............................ $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
Lead Temperature (soldering, 10s) ................................. $+300^{\circ} \mathrm{C}$
Soldering Temperature (reflow) ...................................... $+260^{\circ} \mathrm{C}$

## PACKAGE THERMAL CHARACTERISTICS (Note 1)

## TSSOP

Junction-to-Ambient Thermal Resistance ( $\theta \mathrm{JA}$ )............ $90^{\circ} \mathrm{C} / \mathrm{W}$
Junction-to-Case Thermal Resistance ( $\theta \mathrm{JC}$ )................ $27^{\circ} \mathrm{C} / \mathrm{W}$
Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a fourlayer board. For detailed information on package thermal considerations, refer to www.maxim-ic.com/thermal-tutorial.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS—DUAL SUPPLIES

$\left(\mathrm{V}_{\mathrm{DD}}=+35 \mathrm{~V}, \mathrm{~V}_{S S}=-35 \mathrm{~V}, \mathrm{~V}_{\mathrm{GND}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{L}}=+3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}\right.$ to $+85^{\circ} \mathrm{C}$, unless otherwise noted. Typical values are at $\left.\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}.\right)$

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| POWER SUPPLY |  |  |  |  |  |  |
| VDD Supply-Voltage Range | VDD |  | +10 |  | +35 | V |
| VSS Supply-Voltage Range | VSS |  | -10 |  | -35 | V |
| VL Logic Supply-Voltage Range | VL |  | +1.6 |  | +11 | V |
| VDD Supply Current | IDD(OFF) | $V_{E N}+$ to switch off state, $\mathrm{V}_{\mathrm{A}_{-}}, \mathrm{V}_{\mathrm{B}_{-}}=+20 \mathrm{~V}$ |  | 200 | 450 | $\mu \mathrm{A}$ |
|  | IDD(ON) | $V_{E N}$ _ to switch on state, $\mathrm{V}_{\mathrm{A}_{-}}, \mathrm{V}_{\mathrm{B}_{-}}=+20 \mathrm{~V}$ |  | 500 | 800 |  |
| VSS Supply Current | ISS(OFF) | $V_{E N}+$ to switch off state, $\mathrm{V}_{\mathrm{A}_{-}}, \mathrm{V}_{\mathrm{B}_{-}}=+20 \mathrm{~V}$ |  | 200 | 450 | $\mu \mathrm{A}$ |
|  | ISS(ON) | $\mathrm{V}_{E N}$ _ to switch on state, $\mathrm{V}_{\mathrm{A}_{-}}, \mathrm{V}_{\mathrm{B}_{-}}=+20 \mathrm{~V}$ |  | 500 | 800 |  |
| VL Current | IL | $\begin{aligned} & V_{L}=+11 \mathrm{~V}, \mathrm{~V}_{\text {EN } 1}=\mathrm{V}_{\text {EN2 }}=\mathrm{V}_{\text {EN3 }}=\mathrm{V}_{\text {EN4 }}= \\ & \left(0.25 \times \mathrm{V}_{\mathrm{L}}\right) \text { or }\left(0.75 \times \mathrm{V}_{\mathrm{L}}\right) \end{aligned}$ |  |  | 0.4 | mA |
| SWITCH |  |  |  |  |  |  |
| Analog-Signal Range | $\mathrm{V}_{\mathrm{A}_{-},} \mathrm{V}_{\mathrm{B}_{-}}$ | Figure 1 | VSS |  | VDD | V |
| Current Through Switch | $1 A_{-}, \mathrm{IB}_{-}$ | $\mathrm{V}_{\mathrm{A}_{-}}, \mathrm{V}_{\mathrm{B}_{-}}=+20 \mathrm{~V}$ | -50 |  | +50 | mA |
| On-Resistance | Ron | $\mathrm{I}_{\mathrm{A}_{-},} \mathrm{I}_{\mathrm{B}_{-}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{A}_{-}}, \mathrm{V}_{\mathrm{B}_{-}}= \pm 20 \mathrm{~V}$, Figure 1 |  | 5 | 10 | $\Omega$ |
| On-Resistance Matching Between Channels | $\triangle \mathrm{RON}$ | $\begin{aligned} & I_{A_{-}}, I_{B_{-}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{A}_{-}}, \mathrm{V}_{\mathrm{B}_{-}}= \pm 20 \mathrm{~V}, 0 \mathrm{~V} \\ & (\text { Note } 2) \end{aligned}$ |  | 0.3 | 0.5 | $\Omega$ |
| On-Resistance Flatness | RFLAT(ON) | $\mathrm{IA}_{-}, \mathrm{IB}_{-}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{A}_{-}}, \mathrm{V}_{\mathrm{B}_{-}}= \pm 20 \mathrm{~V}$ |  | 0.004 |  | $\Omega$ |
| On-Leakage Current | IA/B_(ON) | $\mathrm{V}_{\mathrm{B}_{-}}= \pm 20 \mathrm{~V}, \mathrm{~V}_{\mathrm{A}_{-}}=$unconnected, Figure 2 | -5 |  | +5 | nA |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{B}_{-}}= \pm 20 \mathrm{~V}, \mathrm{~V}_{\mathrm{A}_{-}}=\text {unconnected }, \\ & \mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C} \text {, Figure } 2 \end{aligned}$ |  | 0.01 |  |  |
| Off-Leakage Current | IA/B_(OFF) | $\mathrm{V}_{\mathrm{B}_{-}}= \pm 20 \mathrm{~V}, \mathrm{~V}_{\mathrm{A}_{-}}=-20 \mathrm{~V}$, Figure 3 | -2.5 |  | +2.5 | nA |
|  |  | $\mathrm{V}_{\mathrm{B}_{-}}= \pm 20 \mathrm{~V}, \mathrm{~V}_{\mathrm{A}_{-}}=-20 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C},$ Figure 3 |  | 0.01 |  |  |

## Quad SPST +70V Analog Switches

## ELECTRICAL CHARACTERISTICS—DUAL SUPPLIES (continued)

$\left(V_{D D}=+35 \mathrm{~V}, \mathrm{~V}\right.$ SS $=-35 \mathrm{~V}, \mathrm{~V}_{\mathrm{GND}}=0 \mathrm{~V}, \mathrm{~V} \mathrm{~L}=+3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$, unless otherwise noted. Typical values are at $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$. $)$

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| LOGIC (EN1, EN2, EN3, EN4) |  |  |  |  |  |  |
| Input-Voltage Low | VIL |  |  |  | $\begin{gathered} 0.25 x \\ V_{L} \end{gathered}$ | V |
| Input-Voltage High | VIH |  | $\begin{gathered} 0.75 \mathrm{x} \\ \mathrm{VL} \end{gathered}$ |  |  | V |
| Input Leakage Current |  | $\mathrm{V}_{E N}=0 \mathrm{~V}$ or $\mathrm{V}_{\mathrm{L}}$ | -1 |  | +1 | $\mu \mathrm{A}$ |

## DYNAMIC CHARACTERISTICS

| VDD/VSS Power-On Time |  | $R \mathrm{~L}=10 \mathrm{k}$, | 1 |  | $\mu \mathrm{s}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Enable Turn-On Time | ton | $\mathrm{V}_{\mathrm{A}_{-}}, \mathrm{V}_{\mathrm{B}_{-}}= \pm 10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$, Figure 4 | 35 | 60 | $\mu \mathrm{s}$ |
| Enable Turn-Off Time | toff | $\mathrm{V}_{\mathrm{A}_{-}}, \mathrm{V}_{\mathrm{B}_{-}}= \pm 10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$, Figure 4 | 2 | 3 | $\mu \mathrm{s}$ |
| Off-Isolation | VISO | $\begin{aligned} & V_{A_{-}}, V_{B_{-}}=1 \mathrm{~V} R M S, f=100 \mathrm{kHz}, R_{L}=1 \mathrm{k} \Omega, \\ & C_{L}=15 \mathrm{pF} \text {, Figure } 5 \end{aligned}$ | 65 |  | dB |
| Crosstalk | VCT | $R_{S}=R_{L}=1 \mathrm{k} \Omega$, Figure 6 | 96 |  | dB |
| -3dB Bandwidth | BW | $R S=50 \Omega, R L=1 \mathrm{k} \Omega$, Figure 7 | 145 |  | MHz |
| Total Harmonic Distortion Plus Noise | THD+N | $R S=R L=1 \mathrm{k} \Omega, \mathrm{f}=20 \mathrm{~Hz}$ to 20 kHz | 0.001 |  | \% |
| Charge Injection | Q | $\mathrm{A}_{-}, \mathrm{B}_{-}=\mathrm{GND}, \mathrm{CL}^{2}=1 \mathrm{nF}$, Figure 8 | 580 |  | pC |
| Switch-On Capacitance | Cin | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=+50 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{A}_{-}}, \mathrm{V}_{\mathrm{B}_{-}}=+4 \mathrm{~V}, \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ | 40 |  | pF |
| Switch-Off Capacitance | CIN | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=+50 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{A}_{-}}, \mathrm{V}_{\mathrm{B}_{-}}=+4 \mathrm{~V}, \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ | 35 |  | pF |

## DC ELECTRICAL CHARACTERISTICS—SINGLE SUPPLY

$\left(\mathrm{VDD}=+70 \mathrm{~V}, \mathrm{VSS}=\mathrm{V}_{\mathrm{GND}}=\mathrm{OV}, \mathrm{VL}=+3.3 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}\right.$ to $+85^{\circ} \mathrm{C}$, unless otherwise noted. Typical values are at $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$. $)($ Note 2)

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX |  |
| :--- | :---: | :--- | :---: | :---: | :---: | :---: | UNITS

Note 2: Guaranteed by design; not production tested.
Note 3: All parameters in single-supply operation are expected to be the same as in dual-supply operation.

## Quad SPST +70V Analog Switches



Figure 3. Off-Leakage Current
$\qquad$

## Quad SPST +70V Analog Switches



## Quad SPST +70V Analog Switches



Figure 7. Frequency Response


Vout IS THE MEASURED VOLTAGE DUE TO CHARGE
TRANSFER ERROR Q WHEN THE CHANNEL TURNS OFF
$Q=C_{L} \times V_{\text {OUT }}$

Figure 8. Charge Injection

## Quad SPST＋70V Analog Switches

Typical Operating Characteristics
$\left(\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{L}}=+3.3 \mathrm{~V}\right.$ ，unless otherwise noted．）


ON－RESISTANCE vs．VB＿AND TEMPERATURE （SINGLE SUPPLY）



ON－RESISTANCE vs．VB＿AND TEMPERATURE （DUAL SUPPLIES）


ON－LEAKAGE vs．TEMPERATURE



ON－RESISTANCE vs． $\mathbf{V}_{B}$
（SINGLE SUPPLY）


ON－LEAKAGE vs．TEMPERATURE


VL INPUT CURRENT vs．VEN


## Quad SPST +70V Analog Switches




TURN-ON TIME vs. INPUT VOLTAGE


PSRR vs. FREQUENCY


TURN-OFF TIME vs. INPUT VOLTAGE


## Quad SPST +70V Analog Switches



Pin Description

| PIN | NAME | FUNCTION |
| :---: | :---: | :--- |
| 1 | A1 | Terminal A of Switch 1 |
| 2 | B1 | Terminal B of Switch 1 |
| 3 | EN1 | Enable Input of Switch 1. When EN1 is driven high, the switch's state (NO/NC) changes (see Tables 1, 2, <br> and 3). |
| 4 | VSS | Negative Supply Voltage. Bypass VSS to GND with a 1 $\mu$ F ceramic capacitor (100V rated) as close as <br> possible to the pin. |
| 5 | GND | Ground |
| 6 | EN4 | Enable Input of Switch 4. When EN4 is driven high, the switch's state (NO/NC) changes (see Tables 1, 2, <br> and 3). |
| 7 | B4 | Terminal B of Switch 4 |
| 8 | A4 | Terminal A of Switch 4 |
| 9 | A3 | Terminal A of Switch 3 |
| 10 | B3 | Terminal B of Switch 3 |
| 11 | EN3 | Enable Input of Switch 3. When EN3 is driven high, the switch's state (NO/NC) changes (see Tables 1, 2, <br> and 3). |
| 12 | VL | Logic Supply Voltage. Bypass VL to GND with a 1 $\mu$ F ceramic capacitor as close as possible to the pin. |
| 13 | VDD | Positive Supply Voltage. Bypass VDD to GND with a 1 <br> possible ceramic capacitor (100V rated) as close as <br> pin. |
| 14 | EN2 | Enable Input of Switch 2. When EN2 is driven high, the switch's state (NO/NC) changes (see Tables 1, 2, <br> and 3). |
| 15 | B2 | Terminal B of Switch 2 |
| 16 | A2 | Terminal A of Switch 2 |

# Quad SPST +70V Analog Switches 

## Detailed Description

The MAX14756/MAX14757/MAX14758 are analog switches with low on-resistance of $10 \Omega$ (max) that conduct equally well in both directions. All devices have a rail-to-rail analog-signal range. They operate with a single +70 V supply in unipolar applications or $\pm 35 \mathrm{~V}$ dual supplies in bipolar applications. The bipolar supplies can be offset and do not have to be symmetrical.
The MAX14756 is a quad NC SPST switch, the MAX14757 is a quad NO SPST switch, and the MAX14758 has two NO and two NC SPST switches. These switches have $5 \Omega$ (typ) on-resistances and low on-leakage currents of 5 nA (max). The on-resistance flatness is $0.004 \Omega$ (typ). These devices are suitable for a multitude of analog-signal routing and switching applications, and are functonally operational up to $+125^{\circ} \mathrm{C}$ with increased leakage currents.

## Applications Information

## Low-Distortion Audio

The MAX14756/MAX14757/MAX14758 switches, having low RON and very low RON variation with signal amplitude, are well suited for low-distortion audio applications. The Typical Operating Characteristics show Total Harmonic Distortion (THD) vs. Frequency graphs for several signal amplitudes.

## Current Through the Switches

The current flowing through every switch must be limited to $\pm 50 \mathrm{~mA}$ for normal operation. If the current exceeds this limit, an internal leakage current flows from the switch to VSS. Larger input currents do not destroy the device, as long as the Absolute Maximum Ratings are not exceeded.

## Input-Voltage Clamping

For applications that require input voltages beyond the supplies rails, the internal input diodes to VDD and $V_{S S}$ can be used to limit the input voltages. As shown in Figure 9, series resistors can be employed at the inputs to limit the currents flowing into the diodes during undervoltage and overvoltage conditions. Choose the limiting resistors such that the input currents are limited to IIN_(MAX) $=100 \mathrm{~mA}$. The values of the current-limit resistors can be calculated as the larger of RLIM+ and RLIM-.

$$
\begin{aligned}
& R_{\text {LIM }+}=\frac{V_{I N}(M A X)-V_{D D}}{I_{I_{N}}(M A X)} \\
& R_{\text {LIM }-}=\frac{V_{S S}-V_{I N}(M I N)}{I_{I_{N}}(M A X)}
\end{aligned}
$$

Table 1. MAX14756 Truth Table

| LOGIC |  | SWITCH |  |
| :---: | :--- | :---: | :---: |
| EN1 | 0 | A1/B1 | Closed |
| EN2 | 0 | A2/B2 | Closed |
| EN3 | 0 | A3/B3 | Closed |
| EN4 | 0 | A4/B4 | Closed |
| EN1 | 1 | A1/B1 | Open |
| EN2 | 1 | A2/B2 | Open |
| EN3 | 1 | A3/B3 | Open |
| EN4 | 1 | A4/B4 | Open |

Table 2. MAX14757 Truth Table

| LOGIC |  | SWITCH |  |
| :---: | :--- | :--- | :--- |
| EN1 | 0 | A1/B1 | Open |
| EN2 | 0 | A2/B2 | Open |
| EN3 | 0 | A3/B3 | Open |
| EN4 | 0 | A4/B4 | Open |
| EN1 | 1 | A1/B1 | Closed |
| EN2 | 1 | A2/B2 | Closed |
| EN3 | 1 | A3/B3 | Closed |
| EN4 | 1 | A4/B4 | Closed |

Table 3. MAX14758 Truth Table

| LOGIC |  | SWITCH |  |
| :---: | :--- | :---: | :---: |
| EN1 | 0 | A1/B1 | Closed |
| EN2 | 0 | A2/B2 | Open |
| EN3 | 0 | A3/B3 | Open |
| EN4 | 0 | A4/B4 | Closed |
| EN1 | 1 | A1/B1 | Open |
| EN2 | 1 | A2/B2 | Closed |
| EN3 | 1 | A3/B3 | Closed |
| EN4 | 1 | A4/B4 | Open |

During an undervoltage or overvoltage condition, the input impedance is equal to RLIM. The additional power dissipation due to the fault currents needs to be calculated. During an overvoltage or undervoltage clamping condition on one switch input, the other switches of the MAX14756/MAX14757/MAX14758 operate normally.

## Beyond-the-Rail Input

If input voltages are expected to go beyond the supply voltages, but within the absolute maximum supply voltages of the MAX14756/MAX14757/MAX14758, add two diodes in series with the supplies as shown in Figure 10.

## Quad SPST＋70V Analog Switches



Figure 9．Input Overvoltage and Undervoltage Clamping


Figure 10．Beyond－the－Rail Application

During undervoltage and overvoltage events，the internal diodes pull VDD／VSS supplies up／down．An advantage of this scheme is that the input impedance is high and currents do not flow though the MAX14756／MAX14757／ MAX14758 during overvoltage and undervoltage events． The input voltages must be limited to the voltages speci－ fied in the Absolute Maximum Ratings section．

## Chip Information

PROCESS：BiCMOS

## Package Information

For the latest package outline information and land patterns （footprints），go to www．maxim－ic．com／packages．Note that a ＂+ ＂，＂\＃＂，or＂－＂in the package code indicates RoHS status only． Package drawings may show a different suffix character，but the drawing pertains to the package regardless of RoHS status．

| PACKAGE <br> TYPE | PACKAGE <br> CODE | OUTLINE <br> NO． | LAND <br> PATTERN NO． |
| :---: | :---: | :---: | :---: |
| 16 TSSOP | $\mathrm{U} 16+1$ | $\underline{21-0066}$ | $\underline{90-0117}$ |

## Quad SPST +70V Analog Switches

| REVISION <br> NUMBER | REVISION <br> DATE | DESCRIPTION | PAGES <br> CHANGED |
| :---: | :---: | :--- | :---: |
| 0 | $12 / 10$ | Initial release | - |

